LT1007, LT1007A, LT1037, LT1037A LOW-NOISE, HIGH-SPEED, PRECISION OPERATIONAL AMPLIFIERS

D3195, FEBRUARY 1989-REVISED JUNE 1991

- Maximum Equivalent Input Noise Voltage:
 3.8 nV/√Hz at 1 kHz
 - 4.5 nV/√Hz at 10 Hz
- Low Peak-to-Peak Equivalent Input Noise Voltage: 60 nV Typ from 0.1 Hz to 10 Hz
- Slew Rate (LT1037 and LT1037A):
 11 V/μs Min

LT1007A and LT1037A Specifications:

- High Voltage Amplification:
 7 V/µV Min, R_L = 2 kΩ
 3 V/µV Min, R_L = 600 Ω
- Low Input Offset Voltage 25 μV Max
- Low Input Offset Voltage Temperature Coefficient: 0.6 µV/°C Max
- Common-Mode Rejection Ratio: 117 dB Min

description

These monolithic operational amplifiers feature extremely low noise performance and outstanding precision and speed specifications. The typical differential voltage amplification (at $T_A = 25$ °C) of these devices is an extremely high $20 \text{ V/}_{\mu}\text{V}$ driving a $2\text{-k}\Omega$ load to $\pm 12 \text{ V}$ and $12 \text{ V/}_{\mu}\text{V}$ driving a $600\text{-}\Omega$ load to $\pm 10 \text{ V}$.

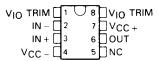
In the design, processing, and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications of even the lowest-cost grades (the LT1007C and the LT1037C) have been greatly improved compared to equivalent grades of competing amplifiers.

DW SMALL-OUTLINE PACKAGE

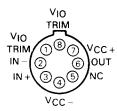
JG AND P DUAL-IN-LINE PACKAGES (TOP VIEW)

9 Пис

NC∏8



L PLUG-IN PACKAGE
(TOP VIEW)



Pin 4 (L Package) is in electrical contact with the case NC – No internal connection

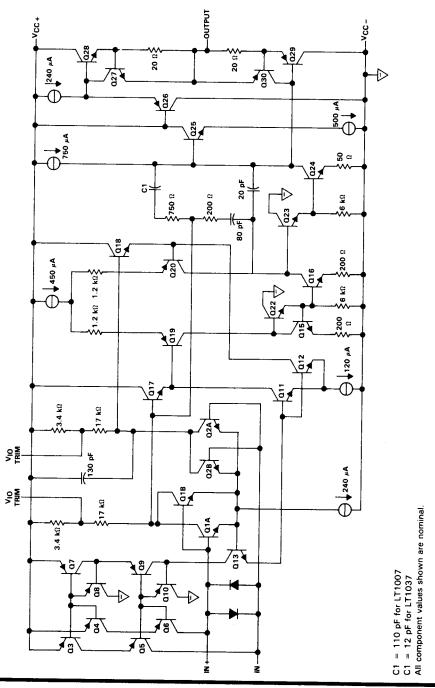
AVAILABLE OPTIONS

		PACKAGE								
TA	V _{IO} MAX AT 25°C	SMALL-OUTLINE (DW)	CERAMIC DIP (JG)	METAL CAN (L)	PLASTIC DIP (P)					
	60 μV	LT1007CDW	_		LT1007CP					
0°C	25 μV	_	-		LT1007ACP					
to	60 μV	LT1037CDW		_	LT1037CP					
70°C	25 μV	_			LT1037ACP					
	60 μV	_	LT1007MJG	LT1007ML	LT1007MP					
– 55°C	25 μV		LT1007AMJG	LT1007AML	LT1007AMP					
to	60 μV	_	LT1037MJG	LT1037ML	LT1037MP					
125°C	25 μV		LT1037AMJG	LT1037AML	LT1037AMP					

The DW packages are available taped and reeled. Add the suffix "R" to the device type, (e.g., LT1007CDWR).



schematic



LT1007, LT1007A, LT1037, LT1037A LOW-NOISE, HIGH-SPEED, PRECISION OPERATIONAL AMPLIFIERS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC+ (see Note 1)
Supply voltage, VCC 22 V
Input voltage
Duration of output short-circuit
Differential input current (see Note 2) ± 25 mA
Power dissipation See Dissipation Rating Table
Operating free-air temperature range:
LT1007C, LT1007AC, LT1037C, LT1037AC0°C to 70°C
LT1007M, LT1007AM, LT1037M, LT1037AM
Storage temperature range65 °C to 150 °C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW and P packages 260 °C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG and L packages 300 °C

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-}.

The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. Excessive
input current will flow if a differential input voltage in excess of approximately ±0.7 V is applied between the inputs, unless
some limiting resistance is used.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE TA = 25°C	TA = 70°C POWER RATING	T _A = 125°C POWER RATING
DW	1025 mW	8.2 mW/°C	656 mW	N/A
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
L	825 mW	6.6 mW/°C	528 mW	165 mW
Р	1000 mW	8 mW/°C	640 mW	200 mW

recommended operating conditions

		C-SUFFIX M-SUFFIX			IX	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}		4	15	22	4	15	22	V
Supply voltage, V _{CC} -		-4	- 15	- 22	-4	- 15	- 22	V
	T _A = 25°C	±11			±11			V
Input voltage, V _I	T _A = full range	± 10.5			±10.3			
Operating free-air temperature, TA		0		70	- 55		125	°C

LT1007C, LT1007AC, LT1037C, LT1037AC LOW-NOISE, HIGH-SPEED, PRECISION OPERATIONAL AMPLIFIERS

electrical characteristics, $V_{CC+} = 15 \text{ V}$, $V_{CC-} = -15 \text{ V}$

	PARAMETER	TEST CONDITIONS	TA	LT1007C, LT1037C			LT1007AC, LT1037AC			UNIT
		1201 00101110110	'A	MIN	TYP	MAX	MiN	TYP	MAX	UNIT
VIO	Input offset voltage	See Note 3	25°C		20	60		10	25	
10		000 14010 0	0°C to 70°C			110			50	μ∨
αVIO	Average temperature coefficient of input offset voltage		0°C to 70°C			1			0.6	μV/°C
10	Input offset current		25°C		12	50		7	30	
10	input offset current		0°C to 70°C			70			40	nΑ
Iв	Input bias current		25°C		±15	±55		± 10	±35	
118	input bias carrent		0°C to 70°C			± 75			±45	nA
l	Peak output voltage	$R_L = 2 k\Omega$	25°C	± 12.5	±13.5		±13	±13.8		
VOM	swing	$R_L = 600 \Omega$	25°C	± 10.5	±12.5		±11	± 12.5		V
		$R_L = 2 k\Omega$	0°C to 70°C	±12			±12.5			
1		$R_L \ge 2 k\Omega$, $V_O = \pm 12 V$	25°C	5	20		7	20		
1	Large-signal	$R_L \ge 1 k\Omega$, $V_O = \pm 10 V$	25°C	3.5	16		5	16		
AVD	differential voltage	$R_L \ge 600 \Omega$, $V_O = \pm 10 V$	25°C	2	12		3	12		V/μV
	amplification	$R_L \ge 2 k\Omega$, $V_O = \pm 10 V$	0°C to 70°C	2.5			4			
		$R_L \ge 1 k\Omega$, $V_O = \pm 10 V$	0°C to 70°C	2			2.5			
ri(CM)	Common-mode input resistance		25°C		5			7		GΩ
ro	Open-loop output resistance		25°C		70			70		Ω
CMRR	Common-mode	V _{IC} = ±11 V	25°C	110	126		117	130		
Civilar	rejection ratio	$V_{IC} = \pm 10.5 V$	0°C to 70°C	106			114			₫₿
ksvr	Supply voltage	V _{CC±} = ±4 V to ±18 V	25°C	106	126		110	130		
~5VH	rejection ratio	$V_{CC\pm} = \pm 4.5 \text{ V to } \pm 18 \text{ V}$	0°C to 70°C	102			106			dB
		LT1007C, LT1007AC	25°C		80	140		80	120	
P_D	Power dissipation	LT1037C, LT1037AC	25°C		85	140		80	130	mW
			0°C to 70°C			160			144	

NOTE 3: V_{IO} measurements are performed by automatic test equipment approximately 0.5 seconds after application of power.

LT1007M, LT1007AM, LT1037M, LT1037AM LOW-NOISE, HIGH-SPEED, PRECISION OPERATIONAL AMPLIFIERS

electrical characteristics, $V_{CC+} = 15 \text{ V}$, $V_{CC-} = -15 \text{ V}$

				LT1007M,		LT	1007AN	1,			
	PARAMETER	TEST CONDITIONS	TA	L	LT1037M		L ⁻	T1037A	4	UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX		
		0 - 1 - 0	25 °C		20	60		10	25	μ٧	
VIO	Input offset voltage	See Note 3	-55°C to 125°C			160			60	μν	
	Average temperature		,				-				
ανιο	coefficient of input		-55°C to 125°C			1			0.6	μV/°C	
	offset voltage										
1	Input offset current		25 °C		12	50		7	30	nA	
li0	input offset current		-55°C to 125°C			85			50		
1	Innut high ourrent		25°C		± 15	± 55		± 10	± 35	nΑ	
ΙΒ	Input bias current		-55°C to 125°C			±95			± 60	110	
	Peak output voltage swing	$R_{L} = 2 k\Omega$	25 °C	± 12.5	± 13.5		±13	±13.8		V	
۷ом		R _L = 600 Ω	25°C	± 10.5	±12.5		±11	±12.5			
		$R_L = 2 k\Omega$	-55°C to 125°C	±12			±12.5				
	Large-signal	$R_L \ge 2 k\Omega$, $V_O = \pm 12 V$	25°C	5	20		7	20			
		$R_L \ge 1 k\Omega$, $V_O = \pm 10 V$	25 °C	3.5	16		5	16			
AVD	differential voltage	$R_L \ge 600 \Omega$, $V_O = \pm 10 V$	25°C	2	12		3	12		V/μV	
	amplification	$R_L \ge 2 k\Omega$, $V_O = \pm 10 V$	-55°C to 125°C	2			3				
		$R_L \ge 1 k\Omega$, $V_O = \pm 10 V$	-55°C to 125°C	1.5			2				
	Common-mode input		25°C		5			7		GΩ	
11(CM)	resistance		25 C		<u> </u>						
	Open-loop output		25°C	ļ	70			70		Ω	
ro	resistance			<u> </u>	,,,						
CMRR	Common-mode	V _{IC} = ±11 V	25 °C	110	126		117	130		dB	
CIVINN	rejection ratio	$V_{IC} = \pm 10.3 \text{ V}$	~55°C to 125°C	104			112				
kovo	Supply voltage	$V_{CC\pm} = \pm 4 \text{ V to } \pm 18 \text{ V}$	25°C	106	126		110	130		dB	
ksvr	rejection ratio	$V_{CC \pm} = \pm 4.5 \text{ V to } \pm 18 \text{ V}$		100			104				
		LT1007M, LT1007AM	25 °C		80	140		80	120		
P_{D}	Power dissipation	LT1037M, LT1037AM	25 °C	ļ <u></u>	85	140		80	130	mW	
			-55°C to 125°C			170			150		

NOTE 3: V_{IO} measurements are performed by automatic test equipment approximately 0.5 seconds after application of power.

LT1007, LT1007A, LT1037, LT1037A LOW-NOISE, HIGH-SPEED, PRECISION OPERATIONAL AMPLIFIERS

operating characteristics $V_{CC\pm} = \pm 15 \text{ V}$, $T_A = 25 \, ^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS		LT1007, LT1007A			LT1037, LT1037A		
	TANAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
SR	Slew rate	$R_L \ge 2 k\Omega$, $A_{VD} \ge 1$ (LT1007, LT1007A)	1.7 2	2.5		4.4		. "	
	Siew rate	$R_L \ge 2 k\Omega$, $A_{VD} \ge 5 (LT1037, LT1037A)$		2.5		11	15		V/μs
VNPF	Peak-to-peak equivalent	f = 0.1 Hz to 10 Hz,		0.00			0.06	0.13	
VNPF	input noise voltage	See Note 4	0.06	0.06	0.13				μ∨
V _n	Equivalent input noise	f = 10 Hz		2.8	4.5		2.8	4.5	—InV/√Hz
٧n	noise voltage	f = 1 kHz		2.5	3.8		2.5	3.8	
	Equivalent input	f = 10 Hz, See Note 5		1.5	4		1.5	4	
l _n	noise current	f = 1 kHz, See Note 5		0.4	0.6		0.4	0.6	pA/√Hz
GDW	Gain bandwidth product	f = 100 kHz	5	8					
GBW	dain bandwidth product	f = 10 kHz, A _V ≥ 15				45	60		MHz

NOTES: 4. See the test circuit and frequency response curve for 0.1 Hz to 10 Hz noise (Figure 39) in the Applications Information section.

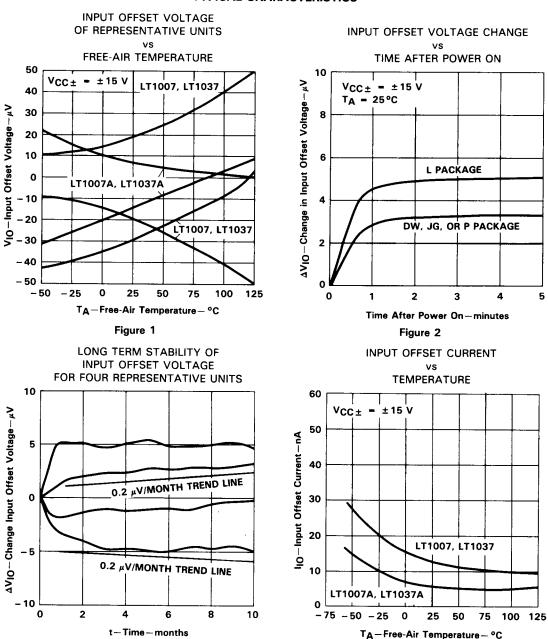
5. See the test circuit for current noise measurement (Figure 40) in the Applications Information section.

TYPICAL CHARACTERISTICS

table of graphs

		- -	FIGURE
VIO	Input offset voltage	vs Temperature	1
		vs Time after power on	2
ΔV_{IO}	Change in input offset voltage	vs Time (long-term stability)	3
lo	Input offset current	vs Temperature	4
		vs Temperature	5
ΙΒ	Input bias current	over common-mode range	6
	Common-mode limit voltage	vs Free-air temperature	7
	Maximum peak output voltage	vs Load resistance	8
Vом	swing	vs Frequency	9
		vs Frequency	10
		vs Frequency (LT1007)	11
		vs Frequency (LT1037)	12
AVD	Differential voltage amplification	vs Temperature	13
••		vs Load resistance	14
		vs Supply voltage	15
		at 2 k Ω and 600 Ω	16
VID	Differential input voltage	vs Output voltage	16
CMRR	Common-mode rejection ratio	vs Frequency	17
ksvr	Supply voltage rejection ratio	vs Frequency	18
		vs Free-air temperature (LT1007)	19
SR	Slew rate	vs Free-air temperature (LT1037)	20
		vs Frequency (LT1007)	11
φ	Phase shift	vs Frequency (LT1037)	12
		vs Free-air temperature (LT1007)	19
ϕ_{m}	Phase margin	vs Free-air temperature (LT1037)	20
		vs Free-air temperature	21
		vs Time (0.01-Hz to 1-Hz noise)	22
V _n	Equivalent input noise voltage	vs Frequency	23
	,	vs Bandwidth	24
		vs Supply voltage	25
	Equivalent input noise current	vs Frequency	26
In	Total noise	vs Source resistance	27
		vs Free-air temperature (LT1007)	19
GBW	Gain bandwidth product	vs Free-air temperature (LT1037)	20
los	Short-circuit output current	vs Time (from short to GND)	28
lcc	Supply current	vs Supply voltage	29
z _o	Closed-loop output impedance	vs Frequency	30
		Small-signal (Cload = 15 pF)	31
	Pulse response (LT1037)	Large-signal	32
		Small-signal (Cload = 15 pF)	33
	Pulse response (LT1007)	Large-signal	34



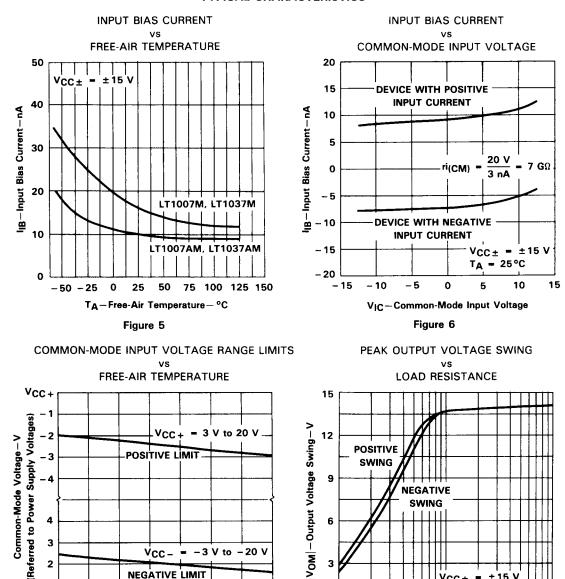


[†]Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

Figure 3



Figure 4



Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

125

100

NEGATIVE LIMIT

50

25

Figure 7

TA-Free-Air Temperature - °C

Vcc-

-50 -25



100

300

10 k

 $V_{CC\pm} = \pm 15$

= 25°C

3 k

TΑ

1 k

R_L-Load Resistance-Ω

Figure 8

TYPICAL CHARACTERISTICS



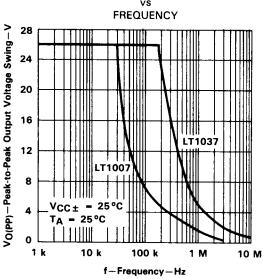


Figure 9

LT1007 DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

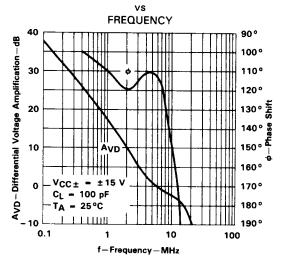


Figure 11

DIFFERENTIAL VOLTAGE AMPLIFICATION

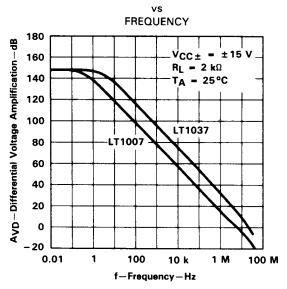


Figure 10

LT1037 DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

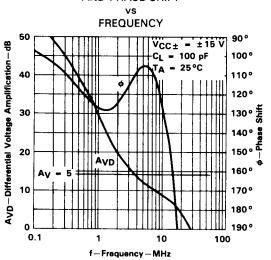
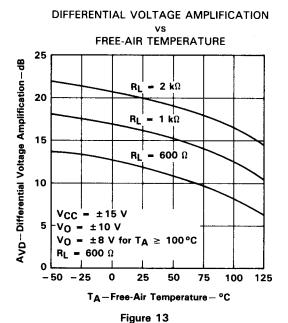


Figure 12



rigure is

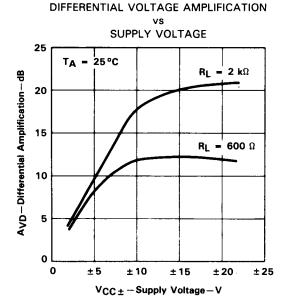
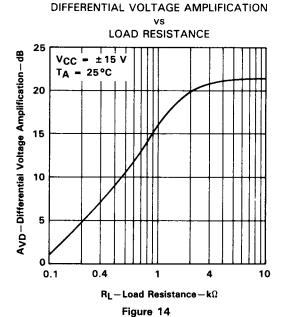


Figure 15



DIFFERENTIAL INPUT VOLTAGE

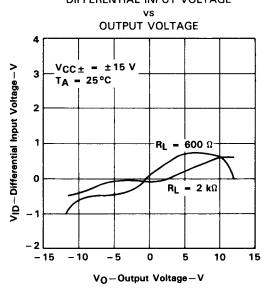
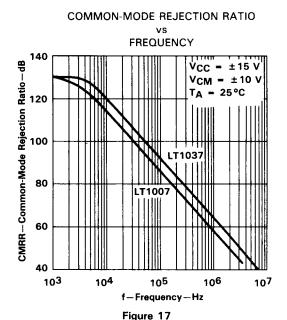


Figure 16

[†]Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



LT1007 SLEW RATE, PHASE MARGIN AND GAIN BANDWIDTH PRODUCT

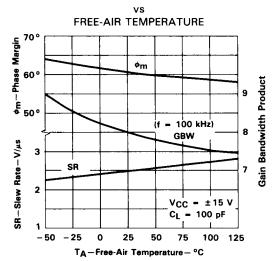


Figure 19

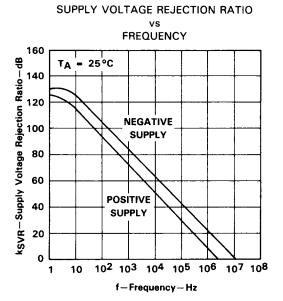
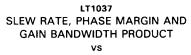


Figure 18



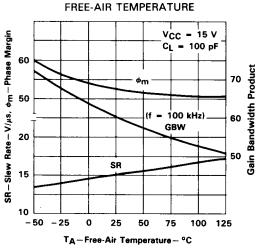
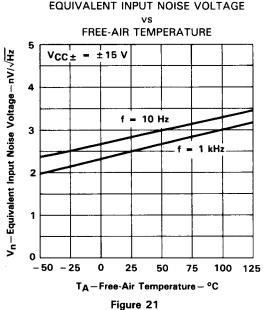


Figure 20

Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



OVER A 100-SECOND TIME PERIOD

f = 0.01 Hz to 1 Hz

40

t-Time-s

60

80

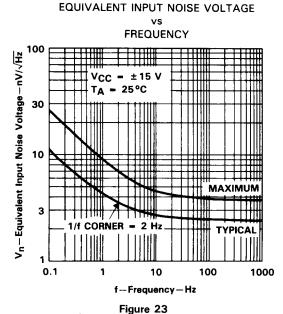
100

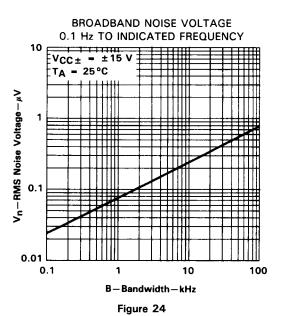
EQUIVALENT INPUT NOISE VOLTAGE

Figure 22

0

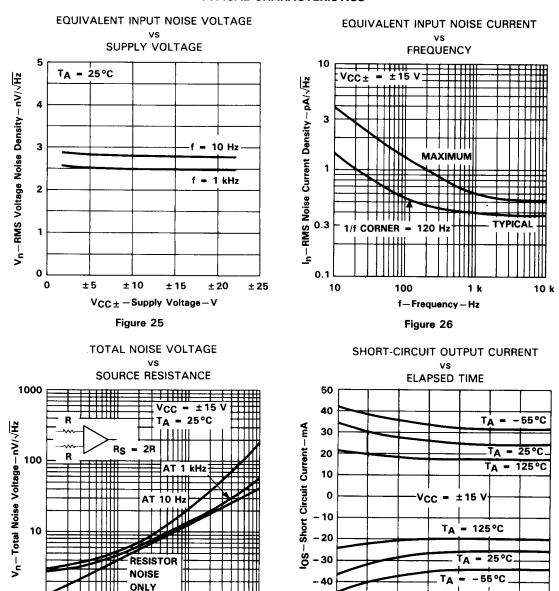
20





[†]Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.





†Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

100

10

Rs-Source Resistance-kΩ

Figure 27



- 50

0

1

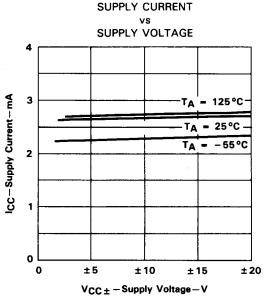
2

Time from Output Short to Ground-minutes

Figure 28

3

0.1



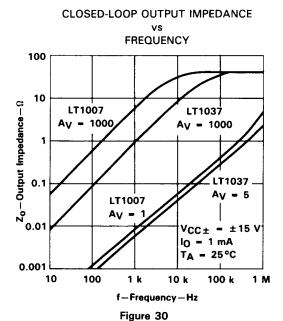


Figure 29 LT1037

VOLTAGE-FOLLOWER

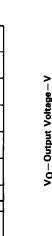
SMALL-SIGNAL PULSE RESPONSE

80

60

-60

-80 0



LT1037 **VOLTAGE-FOLLOWER** LARGE-SIGNAL PULSE RESPONSE

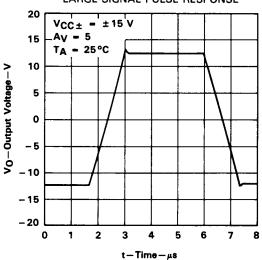


Figure 32

Figure 31

200 400 600 800 1000 1200 1400 1600

t-Time-ns

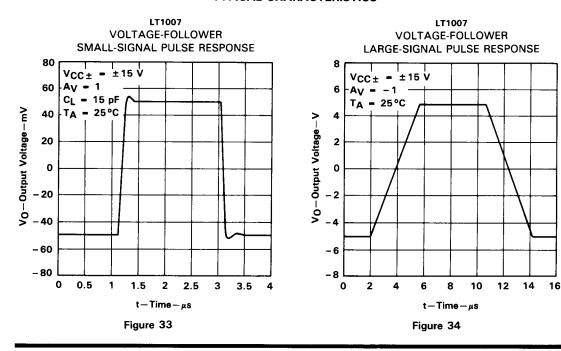
VCC± = ±15 V $A_V = 5$ CL = 15 pF

TA = 25°C

[†]Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS



TYPICAL APPLICATION DATA

general

The LT1007- and LT1037-series devices may be inserted directly into OP-07, OP-27, OP-37, and 5534 sockets with or without removal of external-compensation or nulling components. In addition, the LT1007 and LT1037 may be fitted to μ A741 sockets by removing or modifying external nulling components.

offset voltage adjustment

The input offset voltage and its change with temperature of the LT1007 and LT1037 are permanently trimmed to a low level at wafer testing. However, if further adjustment of VIO is necessary, the use of a 10-kΩ nulling potentiometer, as shown in Figure 35, will not degrade drift with temperature. Trimming to a value other than zero creates a drift of $V_{IO}/300~\mu V/^{\circ}C$ (e.g., if V_{IO} is adjusted to $300~\mu V$, the change in temperature coefficient will be 1 μ V/°C).

The adjustment range with a 10-k Ω potentiometer is approximately ± 2.5 mV. If a smaller adjustment range is needed, the sensitivity and resolution of the nulling can be improved by using a smaller potentiometer in conjunction with fixed resistors. The example in Figure 36 has an approximate null range of $\pm 200 \,\mu V$.

offset voltage and drift

Unless proper care is exercised, thermocouple effects at the contacts to the input terminals, caused by temperature gradients across dissimilar metals, can exceed the inherent temperature coefficient of the amplifier. Air currents should be minimized, package leads should be short, input leads should be close together, and input leads should be at the same temperature.



TYPICAL APPLICATION DATA

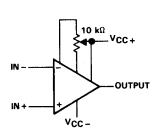


Figure 35. Standard Adjustment

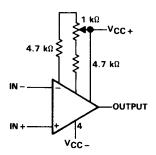


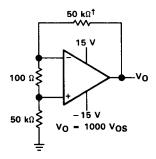
Figure 36. Improved Sensitivity
Adjustment

The circuit shown in Figure 37 can be used to measure offset voltage. In addition, with the supply voltages increased to ± 20 V, it can be used as the burn-in configuration for the LT1007 and LT1037.

When RF \leq 100 Ω and the input is driven with a fast large-signal pulse (>1 V), the output waveform will be as shown in Figure 38.

During the fast-feedthrough-like portion of the output, the input protection diodes effectively short the output to the input and a current, limited only by the output short-circuit protection, is drawn by the signal generator. When RF is $\geq 500 \, \Omega$, the output is capable of handling the current requirements (I_L $\leq 20 \, \text{mA}$ at 10 V), the amplifier stays in its active mode, and a smooth transition occurs.

When RF is > 2 k Ω , a pole will be created with RF and the amplifier's input capacitance, creating additional phase shift and reducing the phase margin. A small capacitor (20 pF to 50 pF) in parallel with RF will eliminate this problem.



[†]Resistors must have low thermoelectric potential

Figure 37. Test Circuit for Offset Voltage and Offset Voltage Drift With Temperature

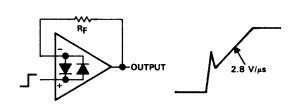
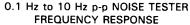


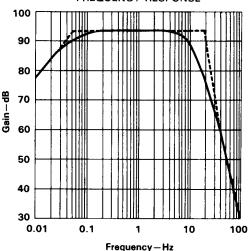
Figure 38. Pulse Operation

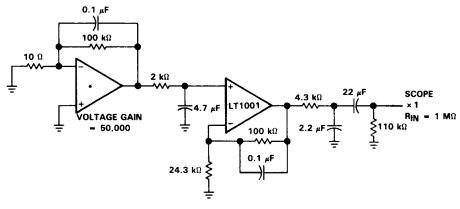
TYPICAL APPLICATION DATA

noise testing

Figure 39 shows a test circuit for 0.1-Hz to 10-Hz peak-to-peak noise measurement of the LT1007 and LT1037. The frequency response of this noise tester indicates that the 0.1 Hz corner is defined by only one zero. Because the time limit acts as an additional zero to eliminate noise contributions from the frequency band below 0.1 Hz, the test time to measure 0.1-Hz to 10-Hz noise should not exceed 10 seconds.







*Device under test

NOTE: All capacitor values are for non-polarized capacitors only.

Figure 39. 0.1-Hz to 10-Hz Noise Test Circuit

TYPICAL APPLICATION DATA

Special test precautions are required to measure the typical 60-nV peak-to-peak noise performance of the LT1007 and LT1037:

- 1. The device should be warmed up for at least five minutes. As the operational amplifier warms up, the offset voltage typically changes 3 μ V, due to the chip temperature increasing 10 °C to 20 °C from the moment the power supplies are turned on. In the 10-second measurement interval, these temperature-induced effects can easily exceed tens of nanovolts.
- 2. The device must be well shielded from air currents to eliminate thermoelectric effects. In excess of a few nanovolts, thermoelectric effects would invalidate the measurements.
- 3. Sudden motion in the vicinity of the device can produce a feedthrough effect that increases observed noise.

When measuring noise on a large number of units, a noise-voltage density test is recommended. A 10-Hz noise-voltage density measurement will correlate well with a 0.1-Hz to 10-Hz peak-to-peak noise reading since both results are determined by the white noise and the location of the 1/f corner frequency.

Figure 40 shows a circuit that measures noise current and presents the formula for calculating noise current.

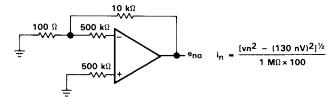


Figure 40. Noise Test Circuit

The LT1007 and LT1037 achieve low noise, in part, by operating the input stage at 120 μ A versus the typical 10 μ A for most other operational amplifiers. Voltage noise is directly proportional to the square root of the stage current; therefore, the LT1007 and LT1037 noise current is relatively high. At low frequencies, the low 1/f current-noise corner frequency (\approx 120 Hz) minimizes noise current to some extent.

In most practical applications, however, noise current will not limit system performance; this is illustrated in Figure 27, where:

total noise = $[(noise \ voltage)^2 \ (noise \ current \times Rs)^2 + (resistor \ noise)^2]^{1/2}$

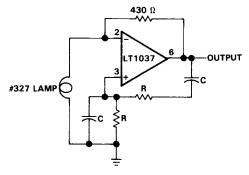
Three regions can be identified as a function of source resistance:

(i) Rs \leq 400 Ω Voltage noise dominates in region (i) Rs = 400 Ω to 50 k Ω at 1 kHz Resistor noise dominates in region (ii) Rs = 400 Ω to 8 k Ω at 10 Hz

(iii) Rs > 50 k Ω at 1 kHz Current noise dominates in region (iii) Rs > 8 k Ω at 10 Hz

The LT1007 and LT1037 should not be used in region (iii) where total system noise is at least six times higher than the noise voltage of the operational amplifier (i.e., the low-voltage noise specification is completely wasted).

The sine wave generator application shown below, utilizes the low-noise and low-distortion characteristics of the LT1037.



 $f = \frac{1}{2\pi RC}$ $R = 1591.5\Omega \pm 0.1\%$ $C = 0.1 \,\mu\text{F} \pm 0.1\%$

TOTAL HARMONIC DISTORTION ≤ 0.0025% NOISE ≤ 0.001%

AMPLITUDE = ±8 V

OUTPUT FREQUENCY = 1.000 kHz FOR VALUES GIVEN ± 0.4%

Figure 41. Ultra-Pure 1-kHz Sine-Wave Generator

EQUIVALENT INPUT NOISE VOLTAGE OVER A 10-SECOND PERIOD

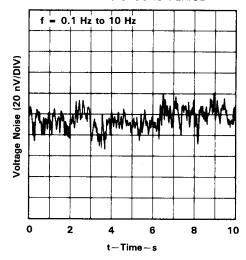
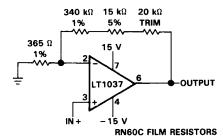
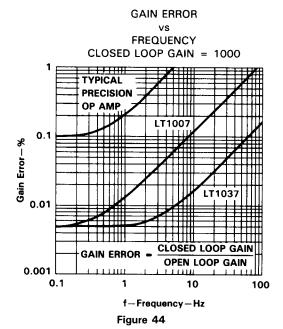


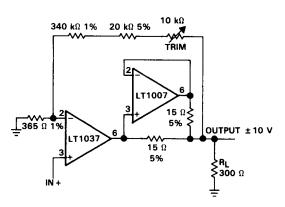
Figure 42



The high gain and wide bandwidth of the LT1037 and (LT1007) is useful in low-frequency high-closed-loop-gain amplifier applications. A typical precision Op Amp may have an open loop gain of one million with 500 kHz bandwidth. As the gain error plot shows, this device is capable of 0.1% amplifying accuracy up to 0.3 Hz only. Even instrumentation range signals can vary at a faster rate. The LT1037's "gain precision—bandwidth product" is 200 times higher, as shown.

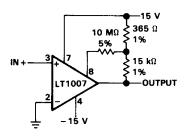
Figure 43. Gain 1000 Amplifier With 0.01% Accuracy, DC to 5 Hz





The addition of the LT1007 doubles the amplifier's output drive to ± 33 mA. Gain accuracy is 0.02%, slightly degraded compared to above because of self heating of the LT1037 under load.

Figure 46. Precision Amplifier Drives 300- Ω Load to \pm 10 V



Positive feedback to one of the nulling terminals creates approximately 5 μV of hysteresis. Output can sink 16 mA.

Input offset voltage is typically changed less than 5 μV due to the feedback.

Figure 45. Microvolt Comparator With Hysteresis

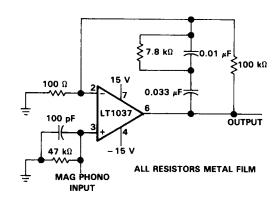


Figure 47. Phono Preamplifier

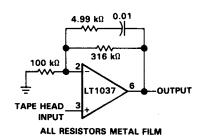


Figure 48. Tape Head Amplifier

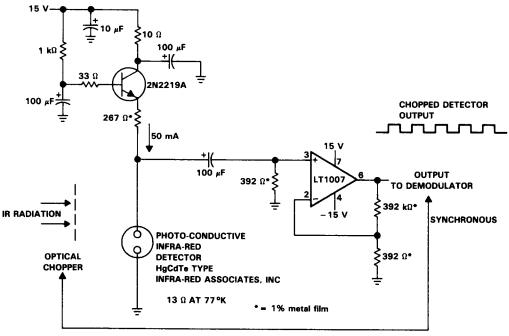


Figure 49. Infra-Red Detector Preamplifier

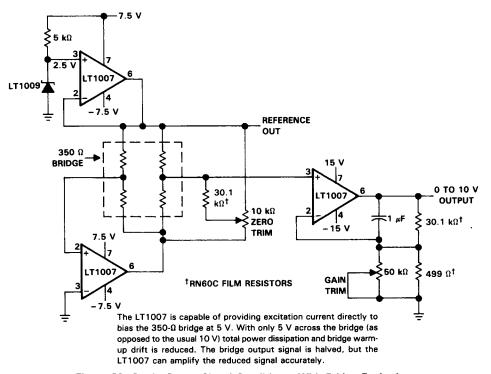


Figure 50. Strain Gauge Signal Conditioner With Bridge Excitation